Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-984-2519

Inclosure Material:

Glass

**Overall Length:** 

0.300 inches

## Terminal Length:

1.000 inches

## **Overall Diameter:**

0.107 inches

## **Mounting Method:**

Terminal

**Features Provided:** 

Hermetically sealed case

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

250.0 breakdown voltage, dc

### **Current Rating Per Characteristic:**

3.00 amperes forward current, average of standard range

### Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

### **Special Features:**

Breakdown volts min

### **Terminal Type And Quantity:**

2 uninsulated wire lead

#### Shelf Life:

N/a

Unit Of Measure:

---

### Demilitarization:

No

# Fiig:

A110a0